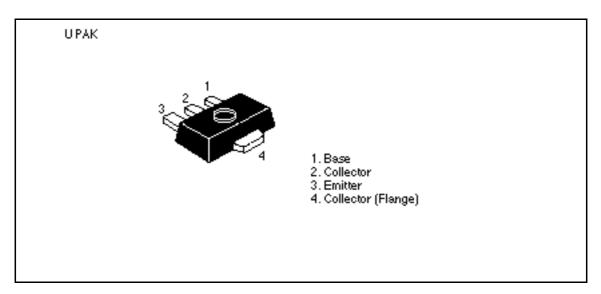
Silicon NPN Epitaxial

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#### Application

- Low frequency power amplifier
- Complementary pair with 2SB1025

#### Outline





#### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	120	V
Collector to emitter voltage	V <sub>CEO</sub>	80	V
Emitter to base voltage	V <sub>EBO</sub>	5	V
Collector current	I <sub>c</sub>	1	А
Collector peak current	i <sub>C(peak)</sub> *1	2	А
Collector power dissipation	P <sub>c</sub> * <sup>2</sup>	1	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

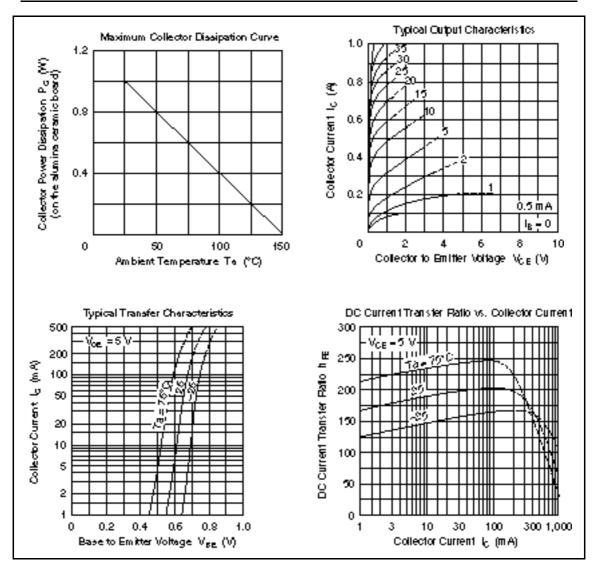
Notes: 1. PW 10 ms, Duty cycle 20%

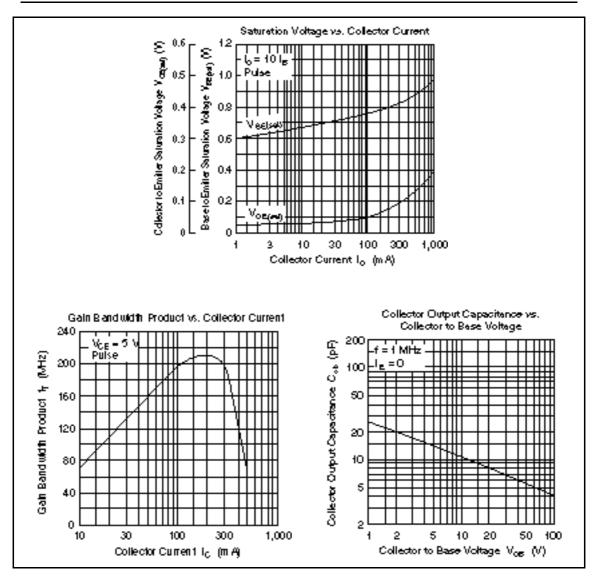
2. Value on the alumina ceramic board (12.5 x 20 x 0.7 mm)

#### **Electrical Characteristics** (Ta = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{\rm (BR)CBO}$	120	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	80	_	_	V	$I_c = 1 \text{ mA}, \text{ R}_{\text{BE}} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	V	$I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_		10	μA	$V_{CB} = 100 \text{ V}, I_{E} = 0$
DC current transfer ratio	$h_{FE1}^{*1}$	60		320		$V_{EB} = 5 \text{ V}, \text{ I}_{C} = 150 \text{ mA}^{*2}$
	h <sub>FE2</sub>	30		_		$V_{ce}$ = 5 V, $I_c$ = 500 mA <sup>*2</sup>
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	—	1	V	$I_{\rm C} = 500$ mA, $I_{\rm B} = 50$ mA* <sup>2</sup>
Base to emitter voltage	$V_{\text{BE}}$	_		1.5	V	$V_{ce}$ = 5 V, $I_c$ = 150 mA <sup>*2</sup>
Gain bandwidth product	$f_{T}$	_	140	_	MHz	$V_{ce}$ = 5 V, $I_c$ = 150 mA <sup>*2</sup>
Collector output capacitance	Cob	_	12	_	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$

Mark	DA	DB	DC
h <sub>FE1</sub>	60 to 120	100 to 200	160 to 320





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